

REMARKS

Applicant respectfully requests that the amendments in this preliminary amendment be made prior to examination of the above-identified application. The application as filed in parent application 10/002,813 had 25 claims. Claims 4-11, 13, 15-18, 20, and 22-25 have been canceled without prejudice; these claims were prosecuted and allowed in parent application 10/002,813. Applicant has amended claims 1-3, 12, 14, 19, and 21. These claims contained recitations directed to the method of fabricating a CMOS circuit by a process capable of fabricating both thin and thick oxide transistors. Applicant has accordingly amended these claims to present them as method claims; new claims 26-31 have been added to further recite the differences between the thin and thick oxide transistors, as described and supported in the specification at pages 5 and 6, for instance.

These amendments and new claims are amply supported by the claims as originally filed and by the discussion of the process fabrication method found in the Brief Summary and at length in the Detailed Description portions of the application as filed. For instance, the Examiner is respectfully directed to page five of the specification, as well as the rest of the Detailed Description.

Drawings

A substitute sheet of formal drawings showing Figures 1 and 2 of the drawings is submitted herewith.

In view of this communication, a first office action is now eagerly awaited at the Examiner's first convenience. The undersigned may be contacted if there are any questions about this filing.

Respectfully submitted,



Renee' Michelle Larson
Registration No. 36,193

Larson and Associates, P.C.
221 East Church Street
Frederick, MD 21701
Phone (301) 668-3073
Fax (301) 668-3074

Dated: 9/26/03

Enclosures